



# Investigation of the low energy excess in SuperCDMS HVeV detectors and its potential subtraction for enhanced dark matter sensitivity

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Osmond Wen

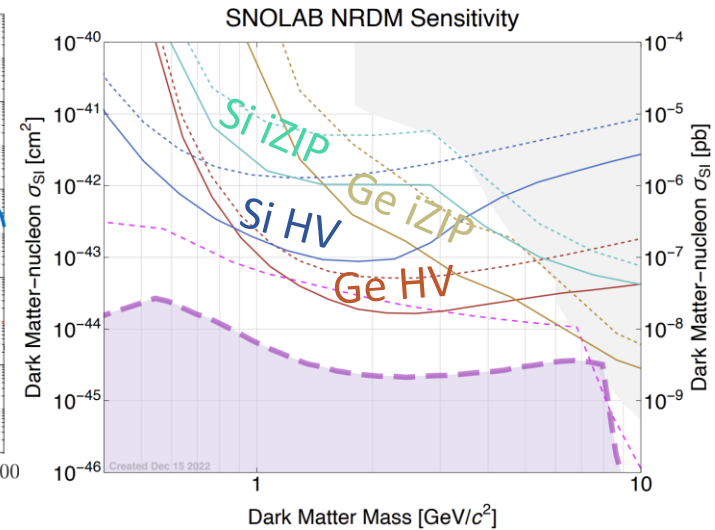
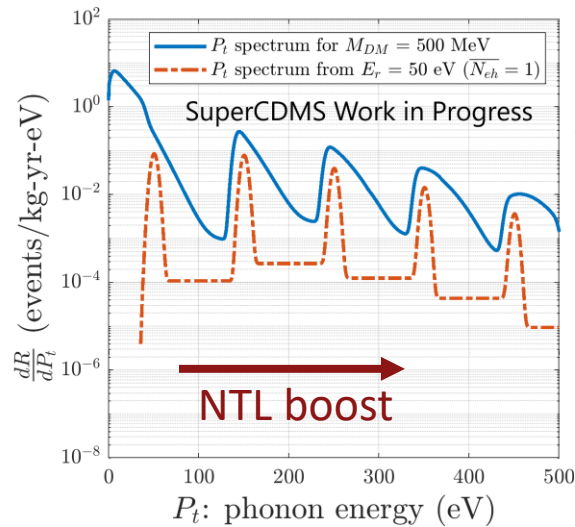
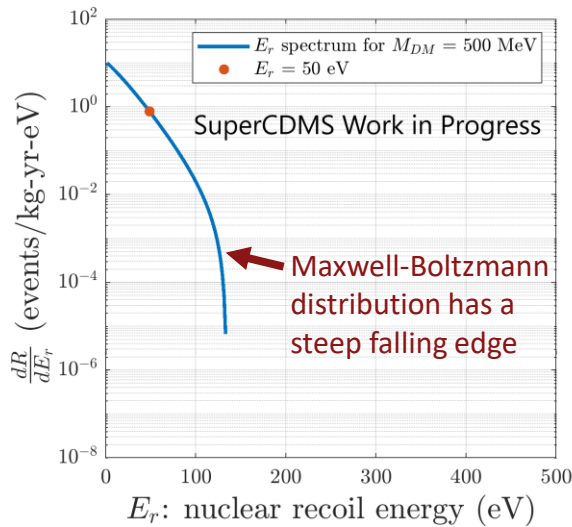
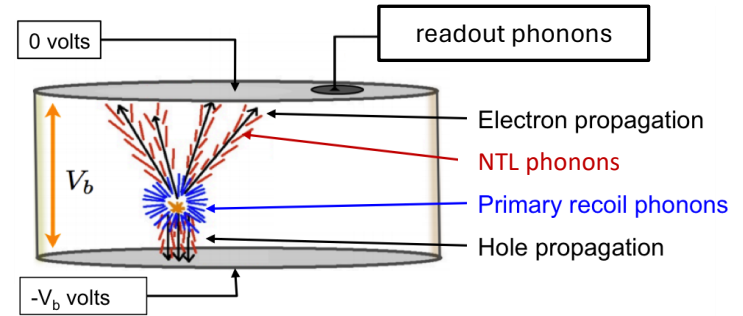
CPAD Workshop 2023

# High voltage operation of phonon-mediated detectors

The Neganov Trofimov Luke (NTL) effect

$$P_t = E_r + N_{eh} e V_b$$

Primary recoil phonons (blue arrow pointing to  $E_r$ )  
 NTL phonons (red arrow pointing to  $N_{eh} e V_b$ )



**SuperCDMS HV detectors will provide the greatest sensitivity to GeV-scale dark matter at SNOLAB due to NTL amplification**

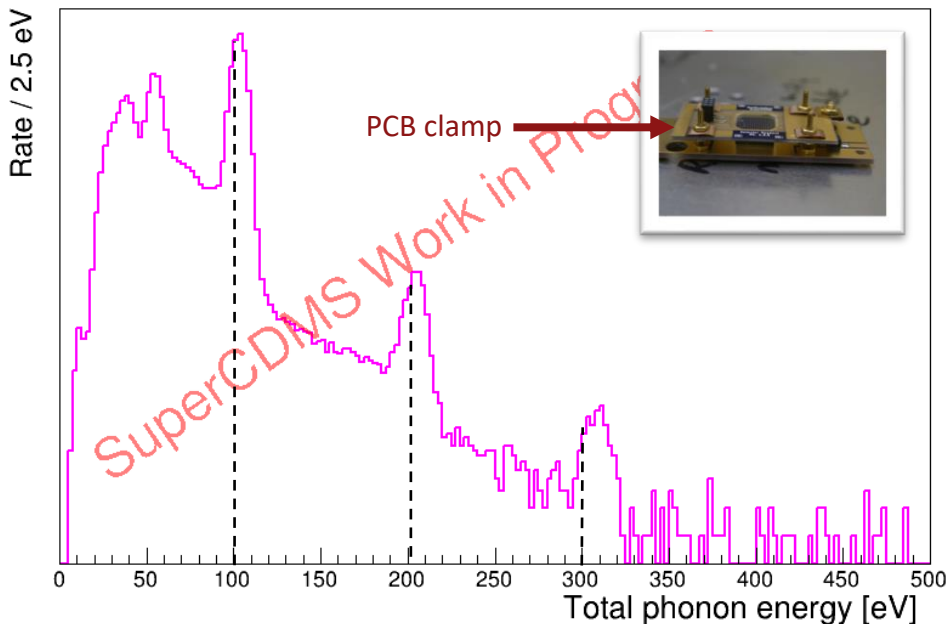


# HV detectors in action

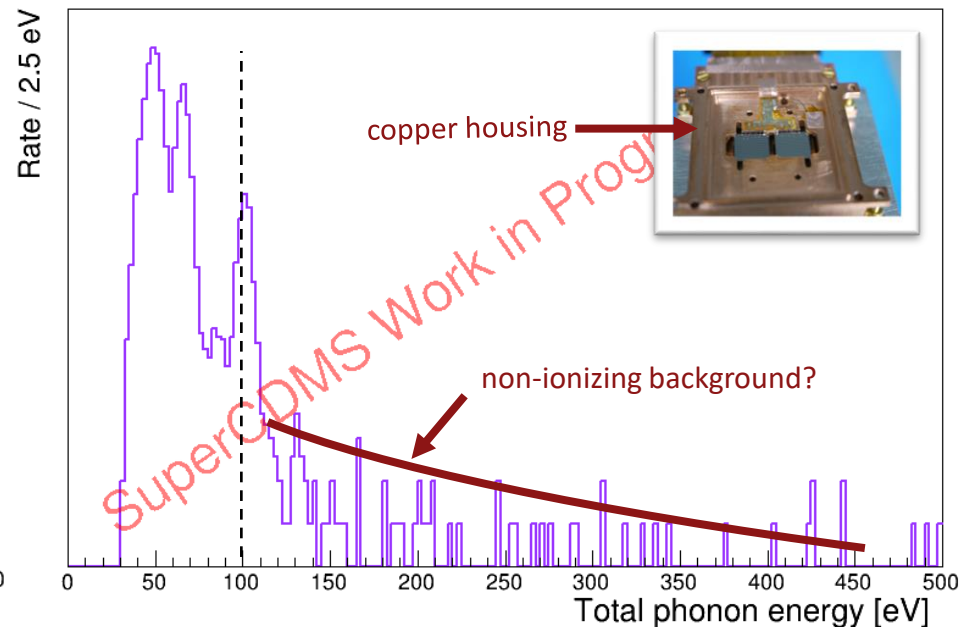
$$P_t = E_r + N_{eh}eV_b$$

- HVeV = prototype of the SuperCDMS SNOLAB HV detector
  - four 1-gram detectors were deployed at the Northwestern Experimental Underground Site (NEXUS)
  - single-charge resolving
  - observed greatly reduced rates of ionizing backgrounds after the removal of an FR4 PCB board
    - we learned that the PCB board was the source of secondary photons
  - non-ionizing backgrounds may dominate the remaining energy spectrum above single charge events: the “low energy excess”

HVeV R3



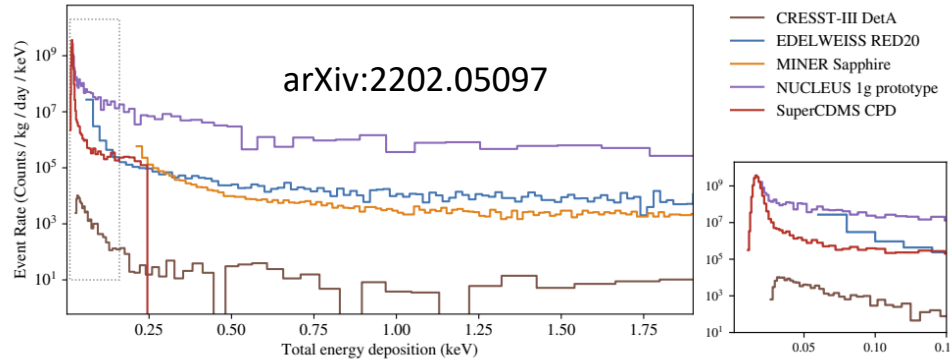
HVeV R4



# The non-ionizing low energy excess: 0QLEE

$$P_t = E_r + N_{eh}eV_b$$

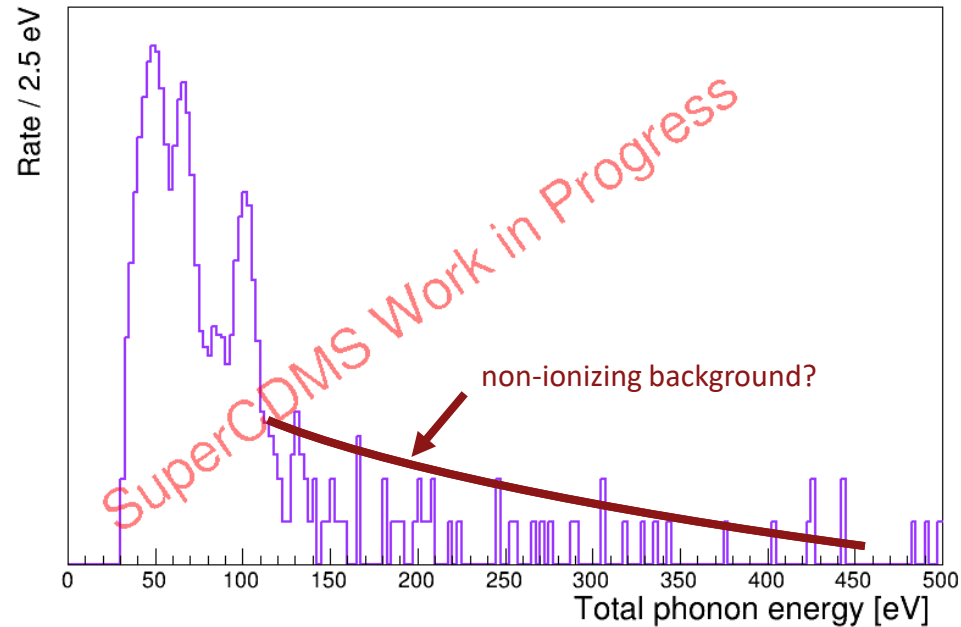
- Many low background experiments observed a rising spectrum of unknown source at low energy



Hypothesized to be due to stress events in the substrate and film

HVeV R4

SuperCDMS has observed greatly decreased rates of ionizing backgrounds in HVeV detectors and may now be limited by 0QLEE

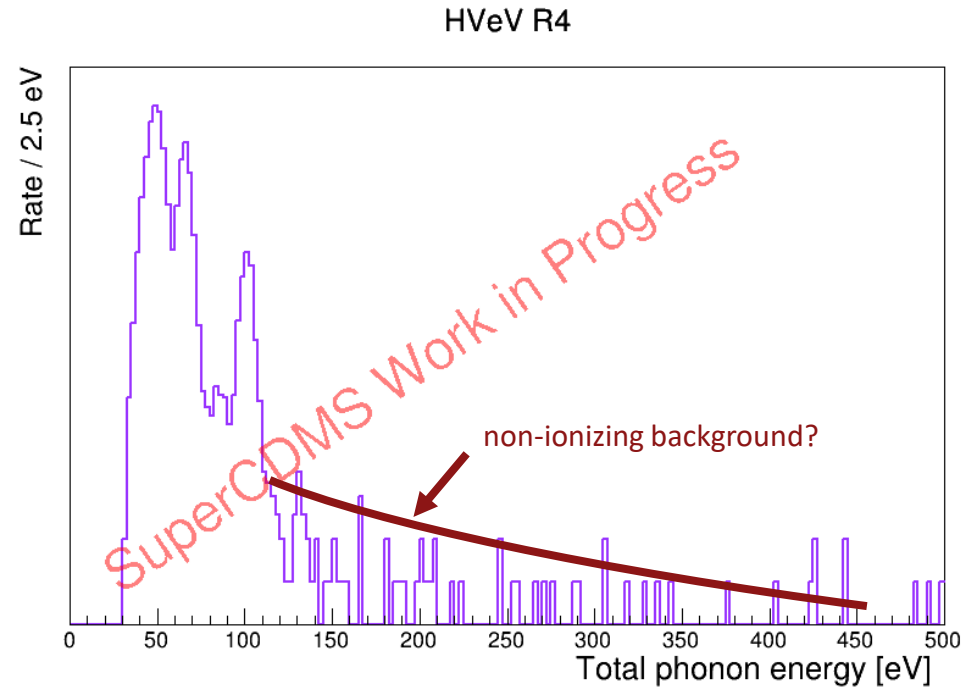
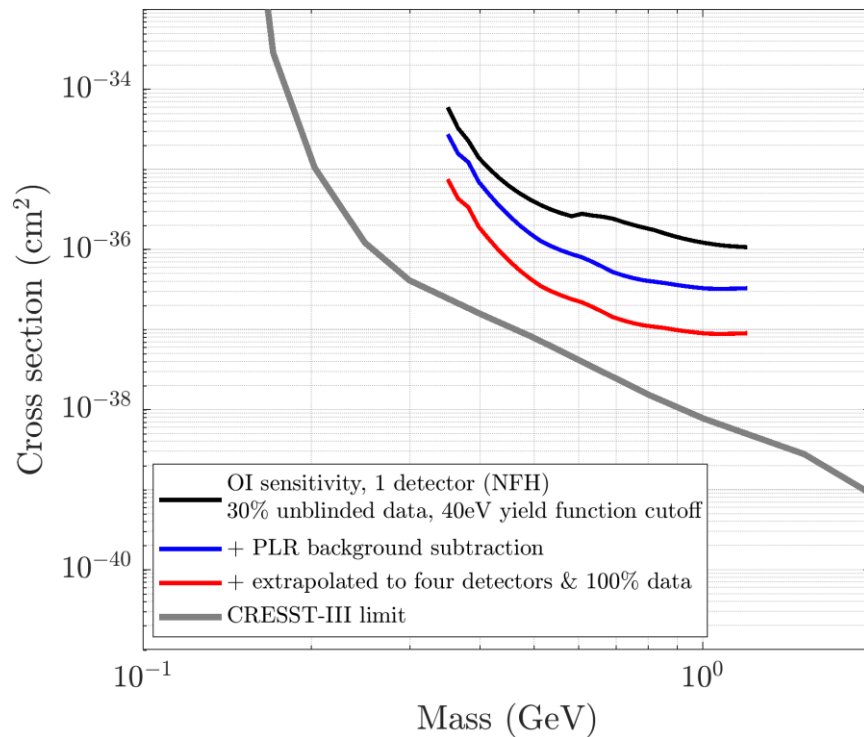


# Sensitivity projection with OQLEE subtraction

$$P_t = E_r + N_{eh}eV_b$$

- As a phonon-mediated detector architecture, HV detectors should also suffer from this low energy excess
- **0V operation may be used to identify the contribution of the low energy excess *in situ* and subtract it for enhanced charge-producing dark matter sensitivity**

blue and red assume OQLEE can be completely subtracted

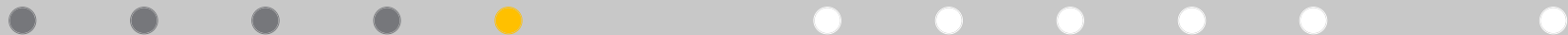
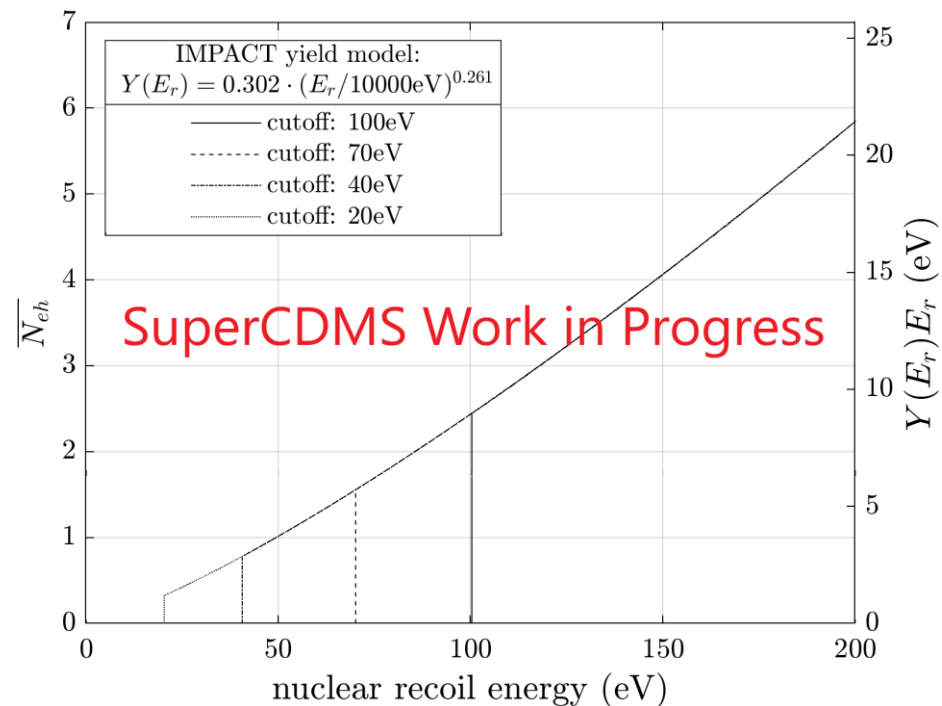
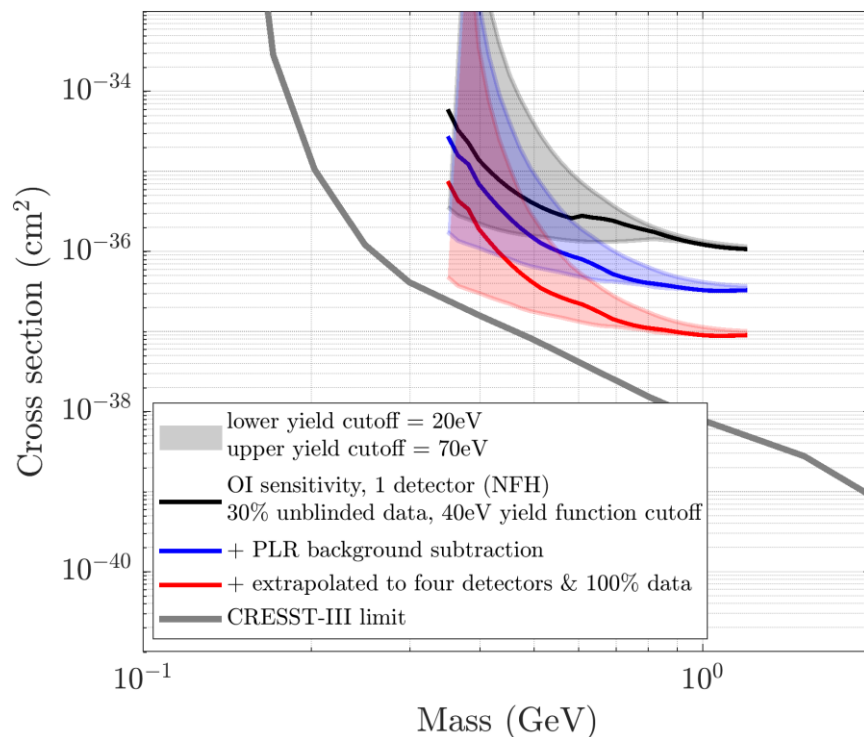


# Sensitivity projection with OQLEE subtraction

$$P_t = E_r + N_{eh}eV_b$$

- As a phonon-mediated detector architecture, HV detectors should also suffer from this low energy excess
- 0V operation may be used to identify the contribution of the low energy excess *in situ* and subtract it for enhanced charge-producing dark matter sensitivity**
- largest systematic uncertainty on the sensitivity is expected to arise from the yield function, which is extrapolated from the IMPACT yield function

blue and red assume OQLEE can be completely subtracted

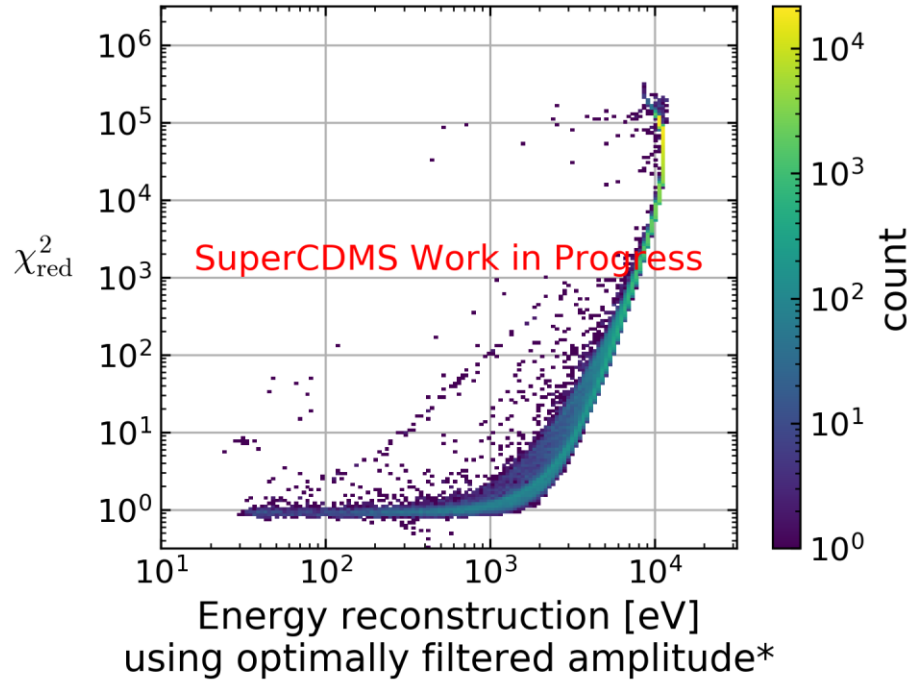


# 0V and HV operation, Cs-137 source

$$P_t = E_r + N_{eh}eV_b$$

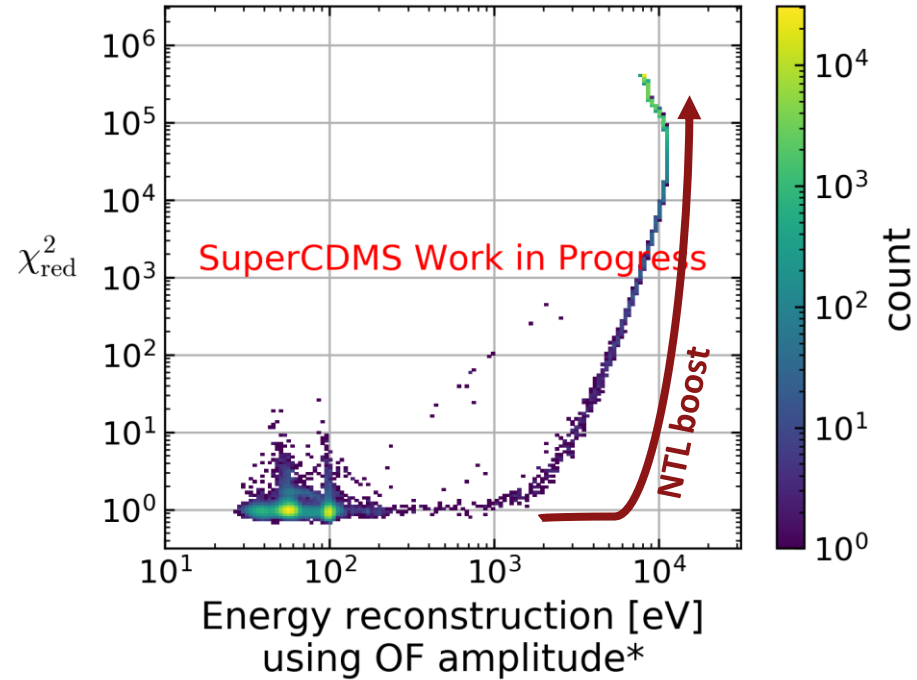
- Recall: HV operation will amplify the phonon response of a particle event via NTL gain

### 0V operation



\*calibrated with 1eh 100 V data

### HV operation



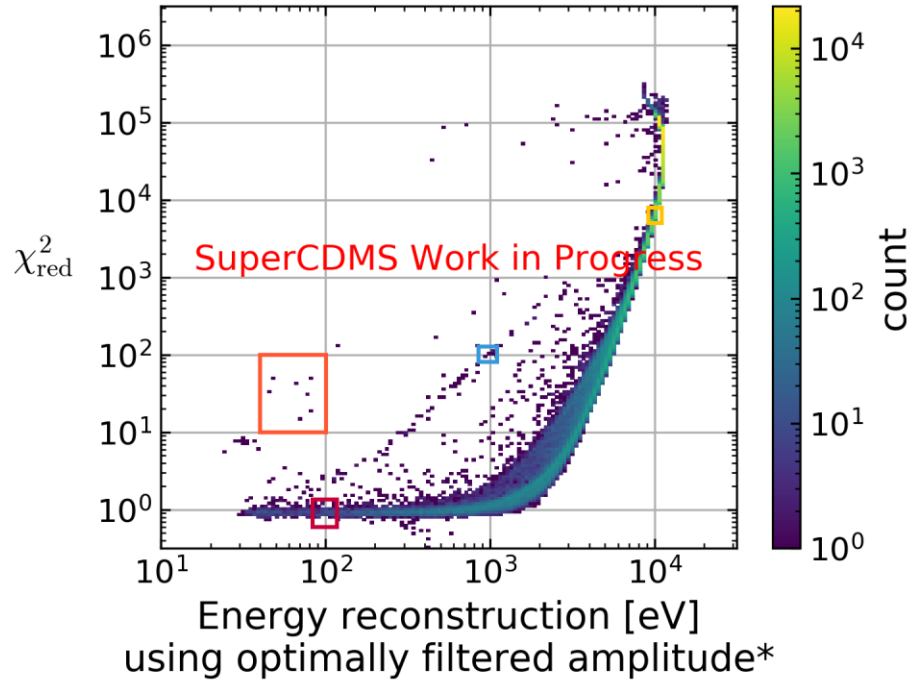
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# 0V operation, Cs-137 source

$$P_t = E_r + N_{eh}eV_b$$

- $\chi^2$ -energy plot shows the various kinds of events that are seen in 0V operation

### 0V operation



\*calibrated with 1eh 100 V data

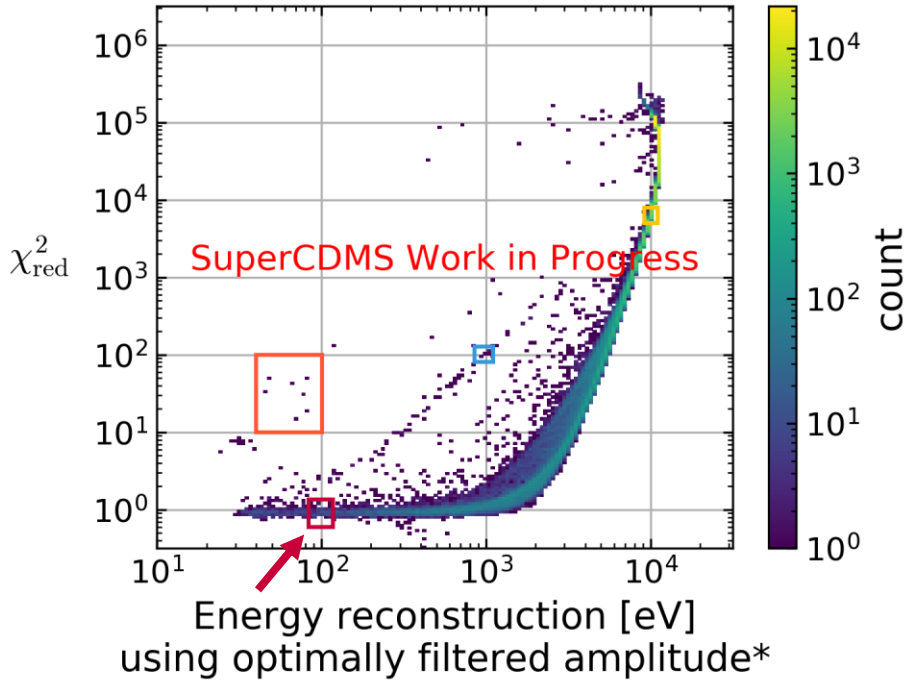


# 0V operation, Cs-137 source

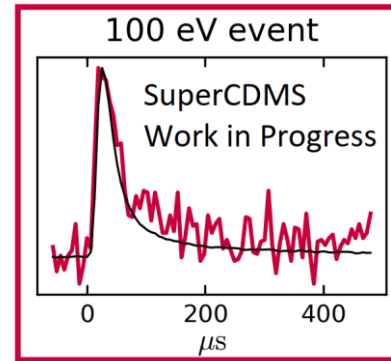
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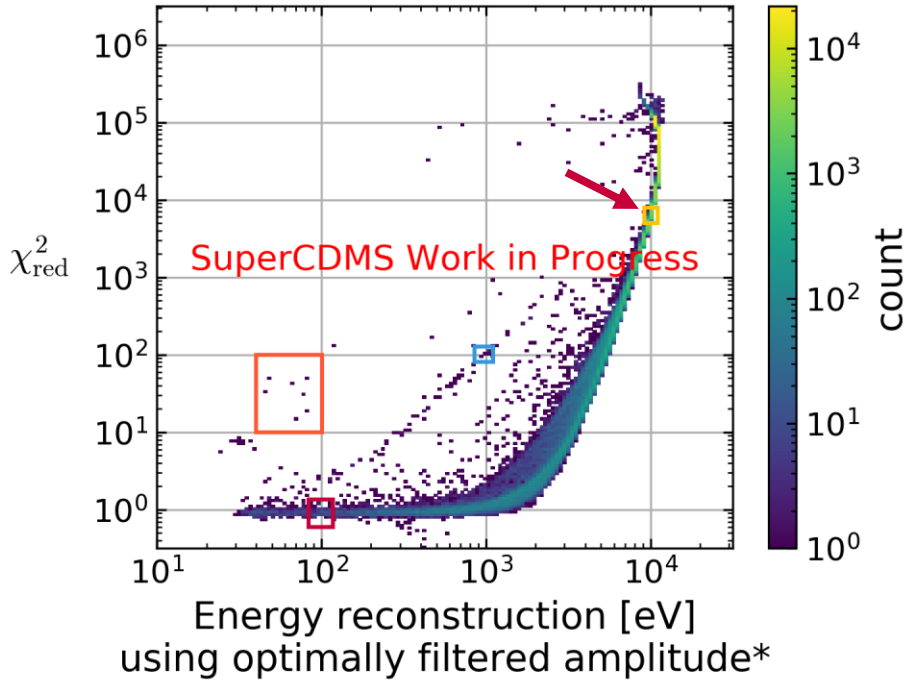


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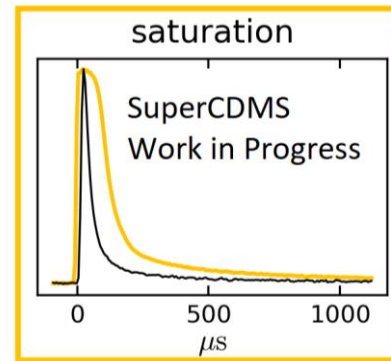
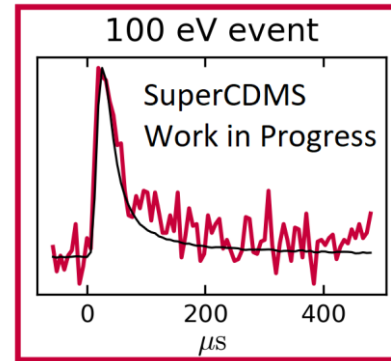
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## 0V operation



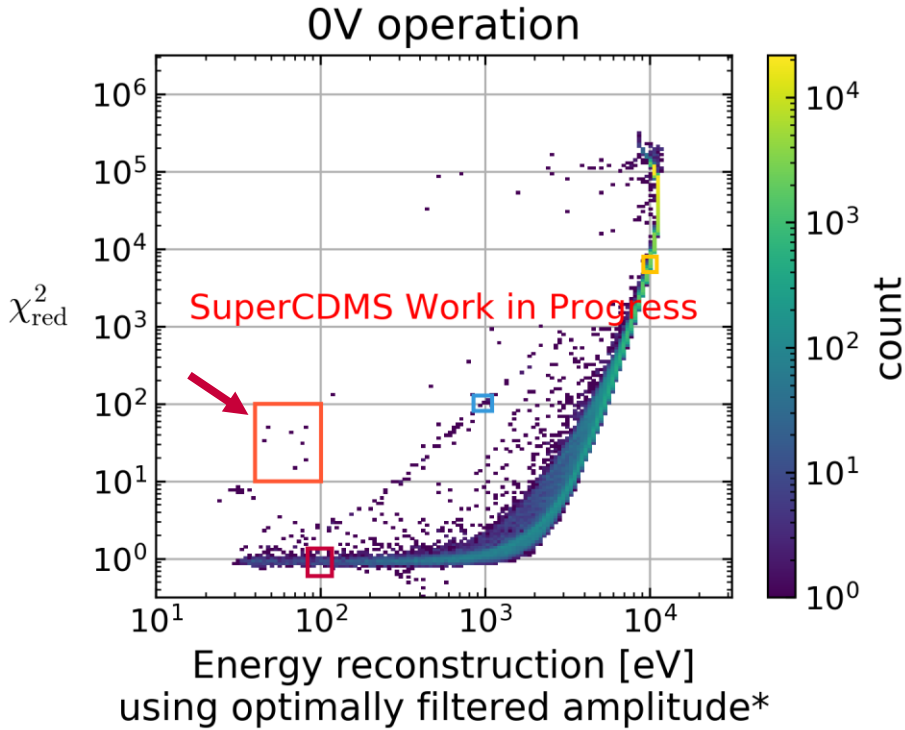
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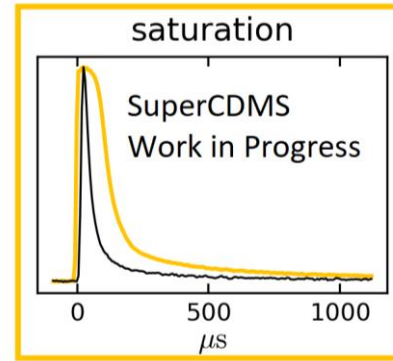
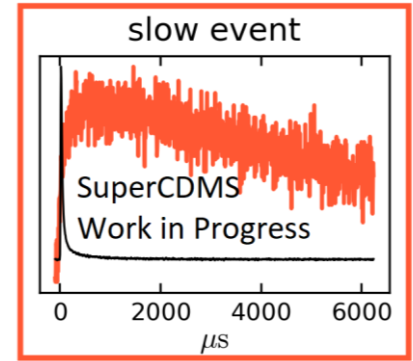
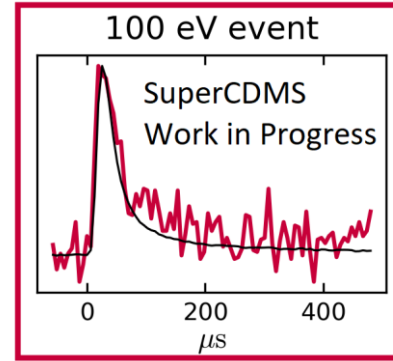
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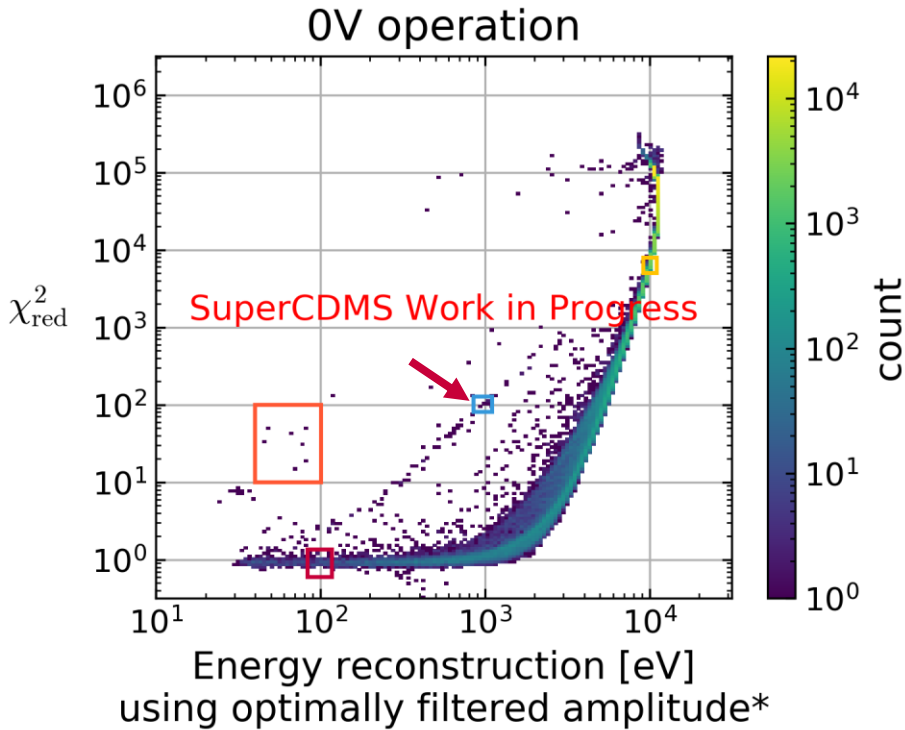
\*calibrated with 1eh 100 V data



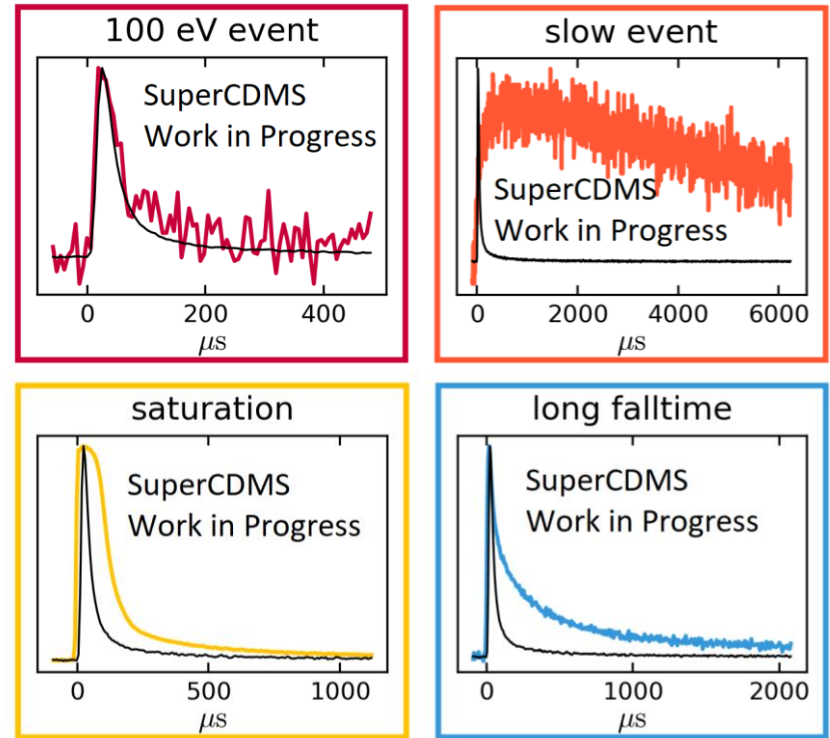
# 0V operation, Cs-137 source

$$P_t = E_r + N_{eh}eV_b$$

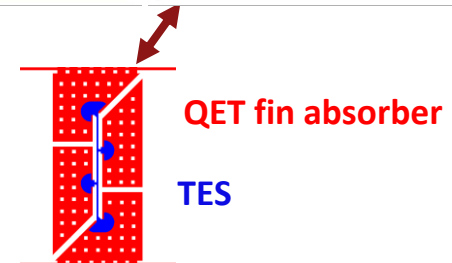
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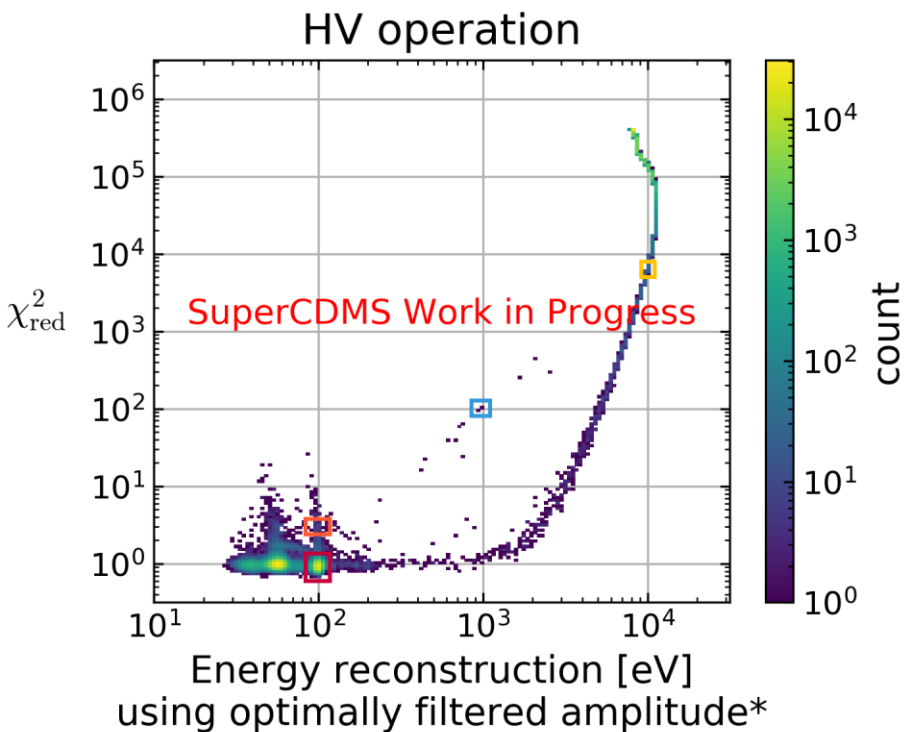
nearby fluorescence?



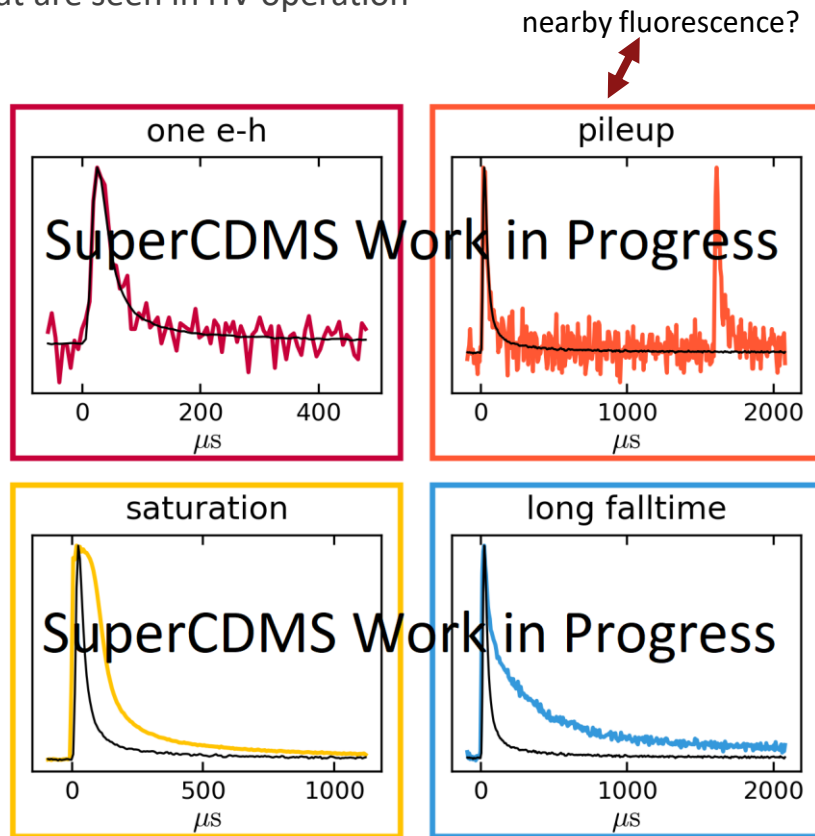
# HV operation, Cs-137 source

$$P_t = E_r + N_{eh}eV_b$$

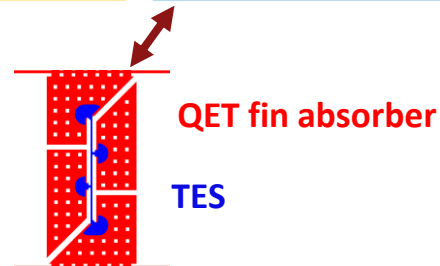
- $\chi^2$ -energy plot shows the various kinds of events that are seen in HV operation



\*calibrated with 1eh 100V data



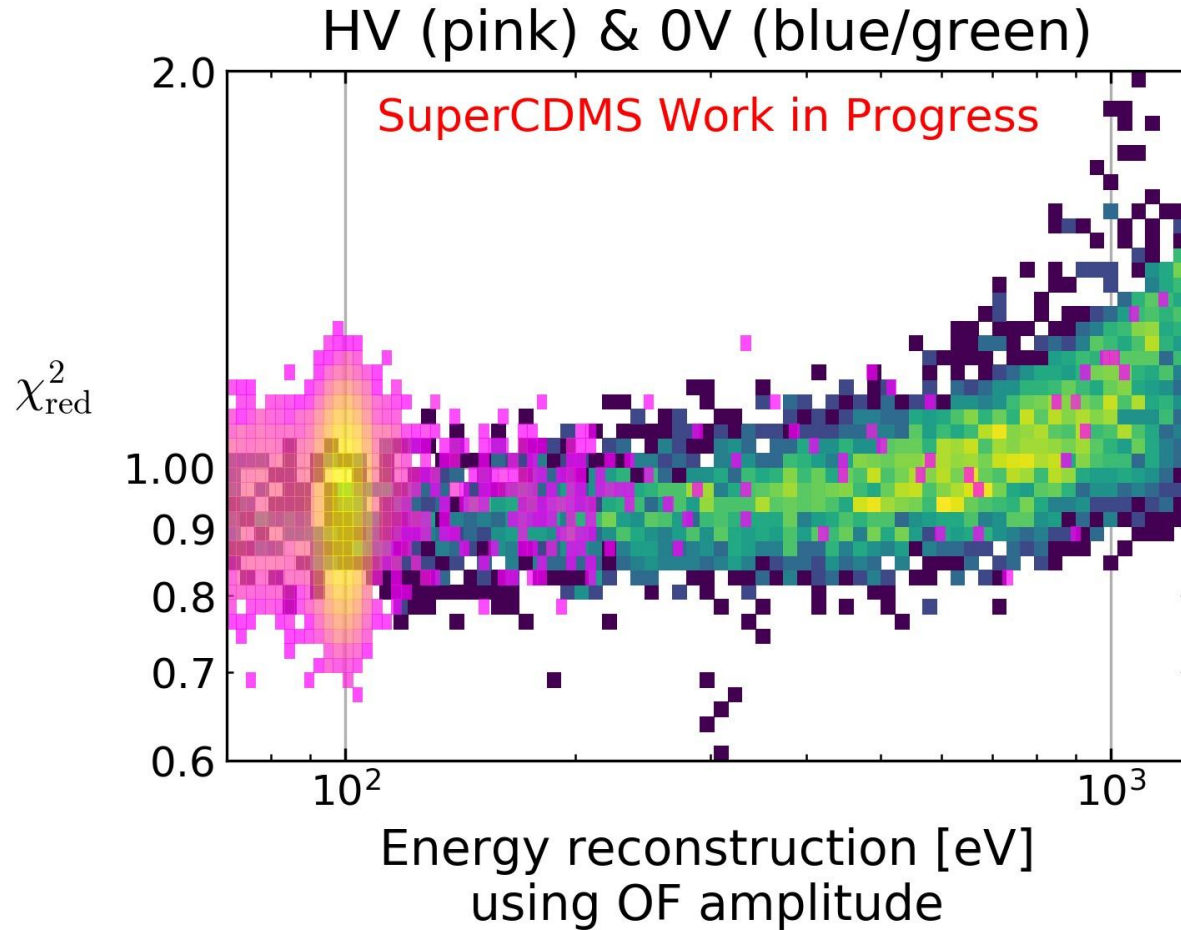
nearby fluorescence?



# 0V vs HV comparison, Cs-137 source

$$P_t = E_r + N_{eh}eV_b$$

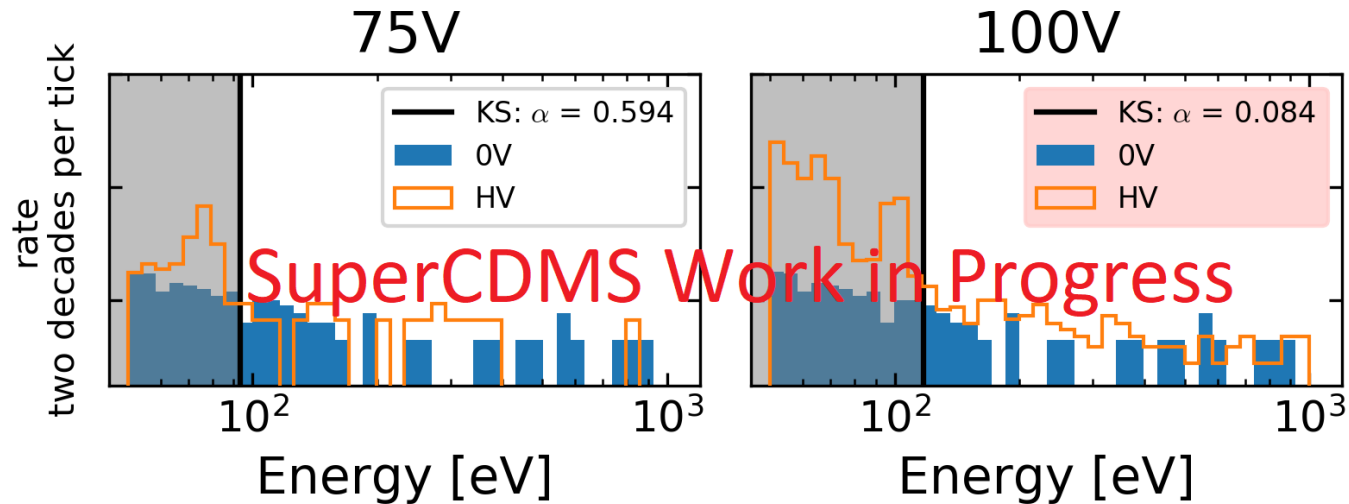
- $\chi^2$ -energy plot after all data quality cuts shows rough consistency between the 0V and HV  $\chi^2$ -distributions versus energy



# 0V vs HV comparison, background data

$$P_t = E_r + N_{eh}eV_b$$

- 0V vs HV background data for one HVeV detector after all data and pulse quality cuts
- Kolmogorov-Smirnov test is applied  $5\sigma$  above the first eh peak
  - 100V fails the KS test – is the spectra perhaps composed of other ionizing events?



- Ideas:
  - Could use more statistics; this is 30% of data
  - What component of the HV data are well-collected charge producing events?
    - Partition cut may help for identifying bulk events
    - Studying the relative rate of saturated events in 0V vs HV may help to understand the effect of the NTL boost
  - Could still consider subtraction of 0QLEE, but would then be background limited by the remaining spectrum

# Summary & outlook

- HV detectors are sensitive to both ionizing and non-ionizing backgrounds
- With greatly decreased rates of ionizing backgrounds, SuperCDMS HVeV backgrounds may be dominated by the 0QLEE
- Subtracting the 0QLEE can lead to enhanced sensitivity
- May yet be other backgrounds in the HV data in excess of the 0V spectrum  $\rightarrow$  requires further study

